

**PHOTON COUPLED ISOLATOR Ga As
 INFRARED EMITTING DIODE &
 LIGHT ACTIVATED SCR**

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 2 available lead forms : -
 - STD
 - G form

DESCRIPTION

The MCS2, MCS2400 are optically coupled isolators consisting of infrared light emitting diode and a light activated silicon controlled rectifier in a standard 6pin dual in line plastic package.

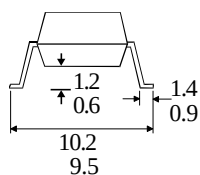
FEATURES

- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape&reel - add SMT&R after part no.
- High Isolation Voltage ($5.3kV_{RMS}$, $7.5kV_{PK}$)
- High Surge Anode Current (5.0 A)
- High Blocking Voltage (200V*1, 400V*1)
- Low Turn on Current (5mA typical)
- All electrical parameters 100% tested
- Custom electrical selections available

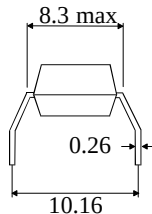
APPLICATIONS

- 10A, T²L compatible, Solid State Relay
- 25W Logic Indicator Lamp Driver
- 400V Symmetrical transistor coupler

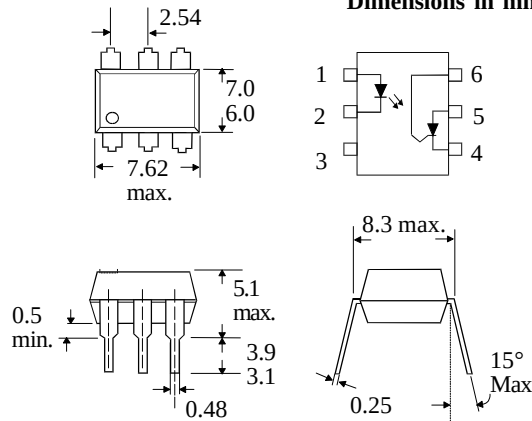
**OPTION SM
 SURFACE MOUNT**



OPTION G



Dimensions in mm



**ABSOLUTE MAXIMUM RATINGS
 (25°C unless otherwise specified)**

Storage Temperature _____ -55°C to + 150°C
 Operating Temperature _____ -55°C to + 100°C
 Lead Soldering Temperature
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

INPUT DIODE

Forward Current _____ 60mA
 Forward Current (Peak)
 (1µs pulse, 300pps) _____ 3A
 Reverse Voltage _____ 6V
 Power Dissipation _____ 100mW

DETECTOR

Peak Forward Voltage
 MCS2 _____ 200V*1
 MCS2400 _____ 400V*1
 Peak Reverse Gate Voltage _____ 6V
 RMS On-state Current _____ 300mA
 Peak On-state Current
 (100µs, 1% duty cycle) _____ 10A
 Surge Current (10ms) _____ 5A
 Power Dissipation _____ 300mW

*1 IMPORTANT : A resistor must be connected between gate and cathode (pins 4 & 6) to prevent false firing ($R_{GK} < 56k\Omega$)

ISOCOM COMPONENTS LTD

Unit 25B, Park View Road West,
 Park View Industrial Estate, Brenda Road
 Hartlepool, Cleveland, TS25 1YD
 Tel: (01429) 863609 Fax : (01429) 863581

ISOCOM INC

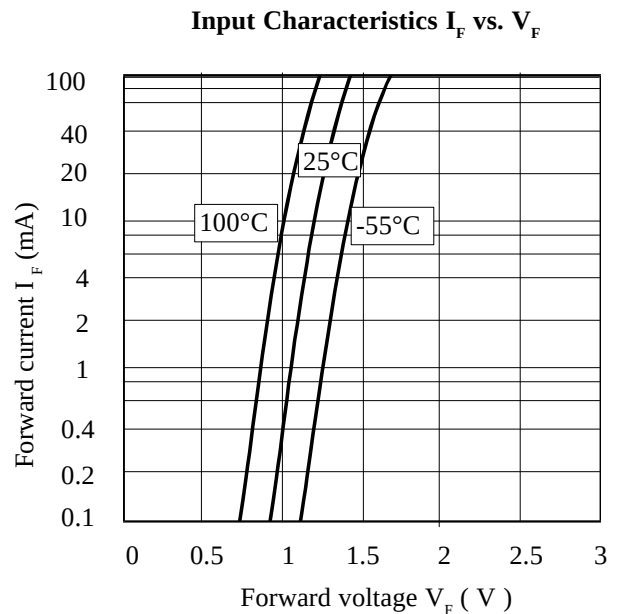
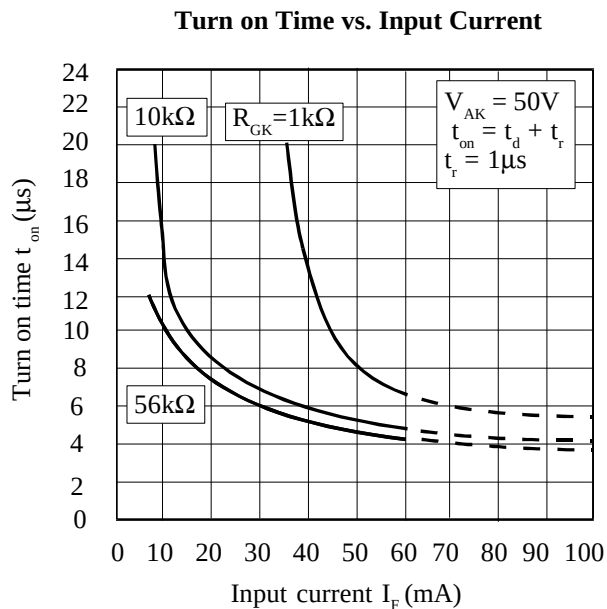
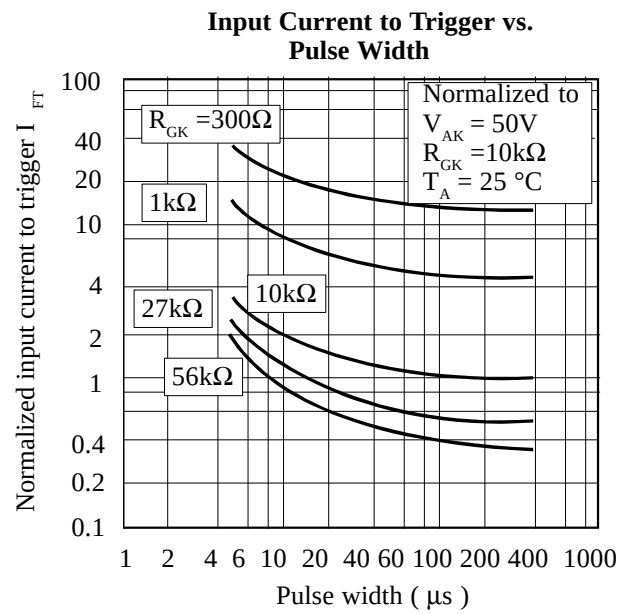
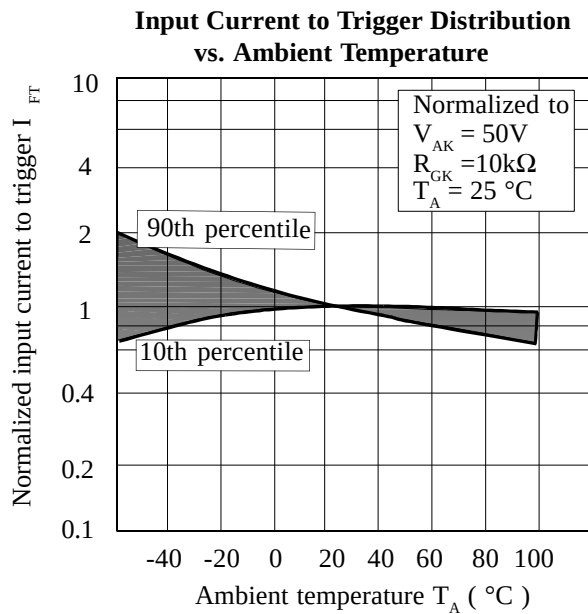
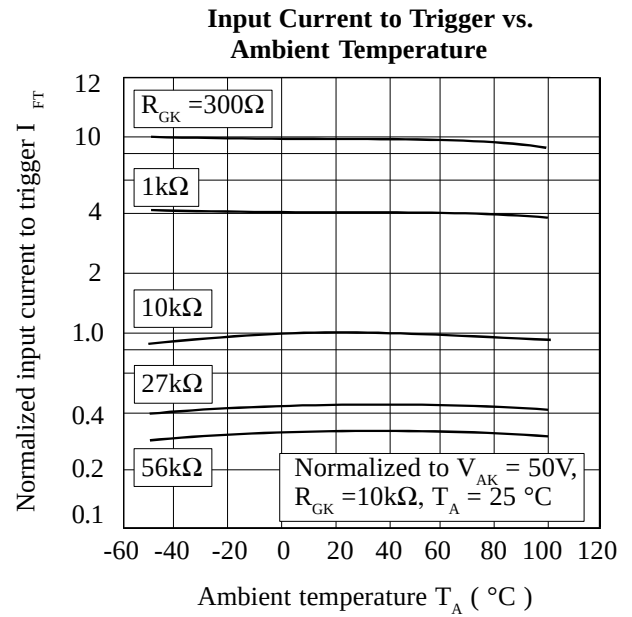
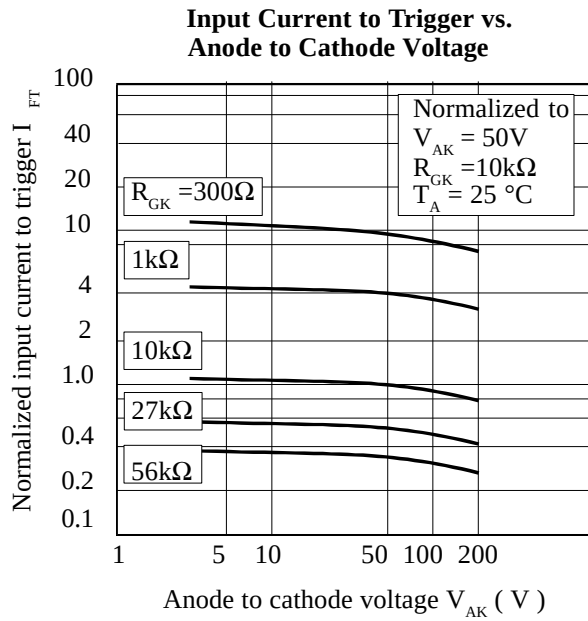
1024 S. Greenville Ave, Suite 240,
 Allen, TX 75002 USA
 Tel: (214) 495-0755 Fax: (214) 495-0901
 e-mail info@isocom.com
 http://www.isocom.com

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

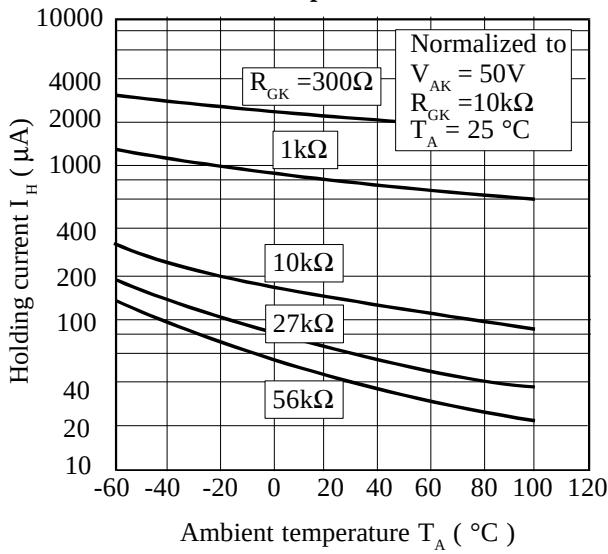
PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	$I_F = 20\text{mA}$
	Reverse Voltage (V_R)	3			V	$I_R = 10\mu\text{A}$
Output (note 2)	Peak Off-state Voltage (V_{DM}) MCS2	200			V	$R_{GK}=10\text{k}\Omega, I_D=150\mu\text{A},$ $T_A = 100^\circ\text{C}$
	MCS2400	400			V	$R_{GK}=10\text{k}\Omega, I_D=150\mu\text{A},$ $T_A=100^\circ\text{C}$
	Peak Reverse Voltage (V_{RM}) MCS2	200			V	$I_D=150\mu\text{A}, T_A=100^\circ\text{C}$
	MCS2400	400			V	$I_D=150\mu\text{A}, T_A=100^\circ\text{C}$
	On-state Voltage (V_{TM}) Off-state Current (I_{DM}) MCS2		1.1	1.3	V	$I_{TM} = 100\text{mA}$
	MCS2400			2	μA	$R_{GK}=27\text{k}\Omega, I_F = 0,$ $V_{DM} = 200\text{V}$
	Reverse Current (I_R) MCS2			2	μA	$R_{GK}=27\text{k}\Omega, I_F = 0,$ $V_{DM} = 400\text{V}$
	MCS2400			2	μA	$I_F = 0, V_{DM} = 200\text{V}$
	MCS2400			2	μA	$I_F = 0, V_{DM} = 400\text{V}$
	Holding Current (I_H)	10		500	μA	$R_{GK}=27\text{k}\Omega, V_{FX}=50\text{V}$
Coupled	Input Current to Trigger (I_{FT}) (note 2)	0.5		14	mA	$V_{AK}=100\text{V}, R_{GK}=27\text{k}\Omega$
	Turn on Time (t_{on})			50	μs	$R_{GK}=10\text{k}\Omega, I_F=30\text{mA},$ $V_{AK}=50\text{V}, R_L=200\Omega$
	Coupled dv/dt, Input to Output (dv/dt)	500			V/ μs	
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO} Input-output Capacitance C_f	10^{11}		2	Ω pF	$V_{IO} = 500\text{V}$ (note 1) $V = 0, f = 1\text{MHz}$

Note 1 Measured with input leads shorted together and output leads shorted together.

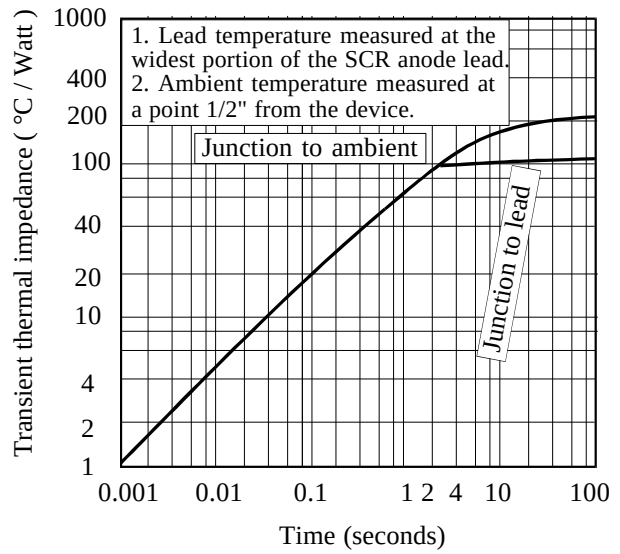
Note 2 Special Selections are available on request. Please consult the factory.



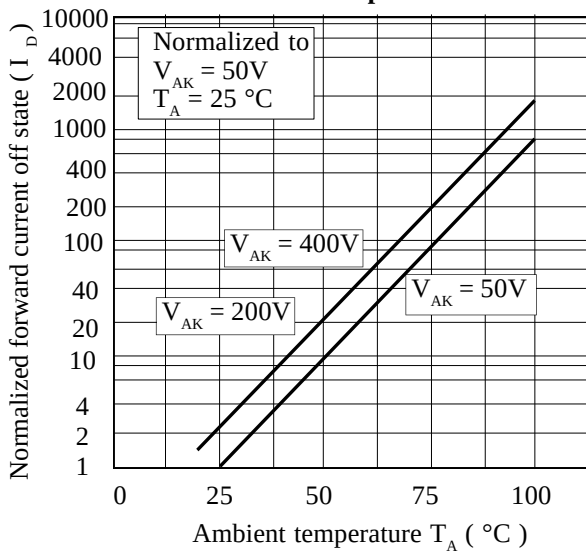
Holding Current vs. Ambient Temperature



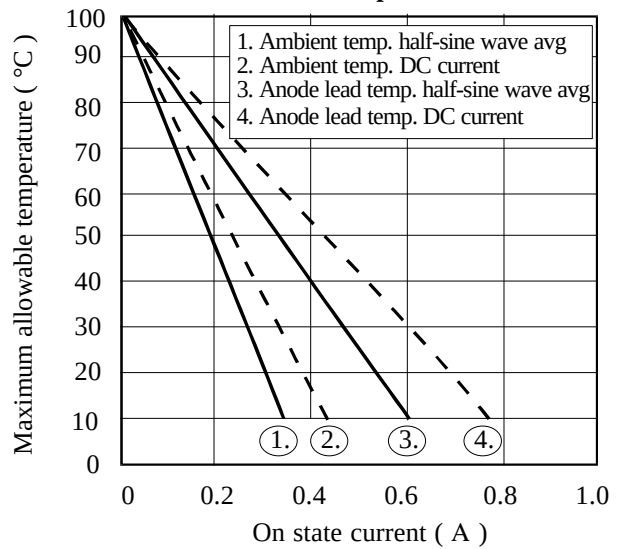
Maximum Transient Thermal Impedance



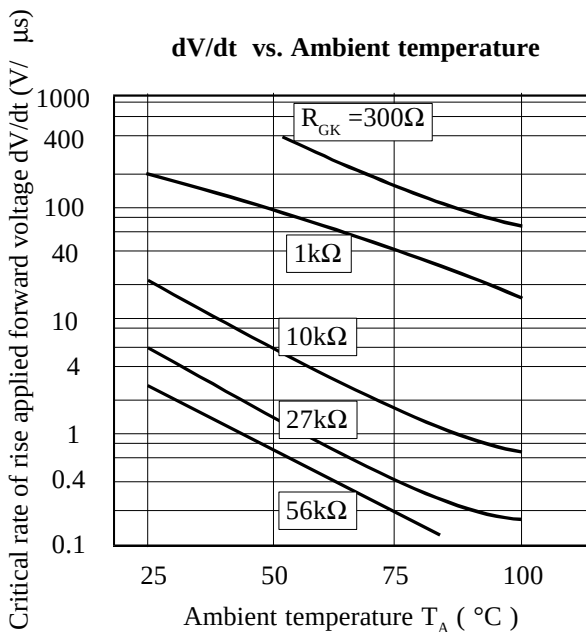
Off State Forward Current vs. Ambient Temperature



On State Current vs. Maximum Allowable Temperature



dV/dt vs. Ambient temperature



On State Characteristics

